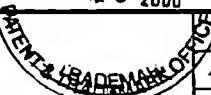


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Application Number	10/572,655
Filing Date	March 20, 2006
First Named Inventor	Dominik EISERT
Art Unit	-- 2811
Examiner Name	Cathy N. Lam

Sheet 1 of 3

Attorney Docket Number 5367-223PUS

## U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. <sup>1</sup>	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind-Code <sup>2</sup> (if known)			
/C.L./		US-2003/0127654 A1	07/10/2003	Eisert et al.	
		US-6,649,939 B1	11/18/2003	Wirth	
		US-6,111,272	08/29/2000	Heinen	
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		US-6,445,010 B1	09/03/2002	Ebeling	
		US-5,200,668	04/06/1993	Ohashi et al.	

Examiner Signature

/Cathy Lam/

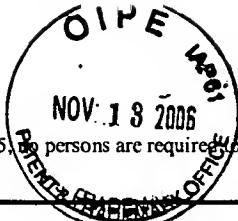
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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet 2 of 3

### Complete if Known

Application Number	10/572,655
Filing Date	March 20, 2006
First Named Inventor	Dominik EISERT
Art Unit	-- 2811
Examiner Name	-- Cathy N. Lam
Attorney Docket Number	5367-223PUS

### FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
		Country Code <sup>3</sup> , Number <sup>4</sup> Kind-Code <sup>5</sup> (if known)				
/C.L./		WO 02/41406 A1	05/23/2002	Eliashevich et al.		
		JP 2001-168387	06/22/2001	Shibata et al.		See English Abstract
		WO 01/61765 A1	08/23/2001	Eisert et al.		
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		WO 01/41225 A2	06/07/2001	Thibeault et al.		
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		DE 101 11 501 A1	09/19/2002	Baur et al.		
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		WO 99/14797	03/25/1999	Lo		
		WO 96/37000	11/21/1996	Heinen		See English Abstract
		WO 96/26550	08/29/1996	Fischer et al.		See English Abstract
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▼		WO 90/05998	05/31/1990	Ohashi et al.		
		DE 100 06 738 A1	09/13/2001	Eisert et al.		

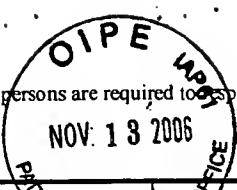
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Sheet 3 of 3		Filing Date	March 20, 2006
		First Named Inventor	Dominik EISERT
		Art Unit	2811
		Examiner Name	Cathy N. Lam
		Attorney Docket Number	5367-223PUS

<b>NON PATENT LITERATURE DOCUMENTS</b>				
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.		T <sup>2</sup>
/C.L./		J. Cao et al., "Improved quality GaN by growth on compliant silicon-on-insulator substrates using metalorganic chemical vapor deposition", Journal of Applied Physics, Vol. 83, No. 7, pp. 3829-3834, April 1, 1998		
		R. Windisch et al., "High-Efficiency Surface-Textured LEDs", Compound Semiconductor, Vol. 6, No. 4, pp. 55-58, May/June 2000		
		Y.K. Song et al., "Resonant-cavity InGaN quantum-well blue light-emitting diodes", Applied Physics Letters, Vol. 77, No. 12, pp. 1744-1746, September 18, 2000		
		A.J. Steckl et al., "Growth and Characterization of GaN Thin Films on SiC SOI Substrates", Journal of Electronics Materials, Vol. 26, No. 3, pp. 217-223, 1997		
		W.S. Wong et al., "Integration of GaN Thin Films with Dissimilar Substrate Materials by Pd-In Metal Bonding and Laser Lift-Off", Journal of Electronic Materials, Vol. 28, No. 12, pp. 1409-1413, 1999		
↓		I. Schnitzer et al., "30% external quantum efficiency from surface textured, thin-film light-emitting diodes", Applied Physics Letter, Vol. 63, No. 18, pp. 2174-2176, October 18, 1993		

Examiner Signature	/Cathy Lam/	Date Considered	09/30/2008
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